



## **SPECIFICATION**

• Supplier : Samsung electro-mechanics • Samsung P/N : CL31C680KBCNBND

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 68pF, 50V, ±10%, C0G, 1206

## A. Samsung Part Number

<u>CL</u> <u>31</u> <u>C</u> <u>680</u> <u>K</u> <u>B</u> <u>C</u> <u>N</u> <u>B</u> <u>N</u> <u>D</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

1	Series	Samsung Multi-layer Ceramic Capacitor		
2	Size	1206 (inch code)	L: 3.2 ± 0.15 mm W	V: 1.6 ± 0.15 mm
3	Dielectric	C0G	8 Inner electrode	Ni
4	Capacitance	<b>68</b> pF	Termination	Cu
(5)	Capacitance	±10 %	Plating	Sn 100% (Pb Free)
	tolerance		Product	Array(4-element)
6	Rated Voltage	50 V	Special	Reserved for future use
7	Thickness	0.85 ± 0.15 mm	ft Packaging	Cardboard Type,13"reel(10,000ea)

## **B. Samsung Reliability Test and Judgement condition**

	Performance	Test condition		
Capacitance	Within specified tolerance	1Mb±10% 0.5~5Vrms		
Q	1000 min			
Insulation	More than 500Mohm⋅ <i>μ</i> Γ	Rated Voltage 60~120 sec.		
Resistance				
Appearance	No abnormal exterior appearance	Visual inspection		
Withstanding	No dielectric breakdown or	300% of the rated voltage		
Voltage	mechanical breakdown			
Temperature C0G				
Characteristics	(From -55℃ to 125℃, Capacitance change should be within ±30PPM/℃)			
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.		
of Termination	terminal electrode			
Bending Strength	Capacitance change: within ±5%	Bending to the limit (1mm)		
		with 1.0mm/sec.		
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder		
	is to be soldered newly	245±5°C, 3±0.3sec.		
		(preheating : 80~120 ℃ for 10~30sec.)		
Resistance to	Capacitance change: within ±2.5%	Solder pot : 270±5℃, 10±1sec.		
Soldering heat	Tan δ, IR : initial spec.			

	Performance	Test condition
Vibration Test Capacitance change: within ±2.5%		Amplitude : 1.5mm
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)
		2hours × 3 direction (x, y, z)
Moisture	Capacitance change: within ±7.5%	With rated voltage
Resistance	Q: 200 min	40±2℃, 90~95%RH, 500 +12/-0 hour
	IR : More than 25№ μF	
High Temperature	Capacitance change: within ±3%	With 200% of the rated voltage
Resistance	Q: 350 min	Max. operating temperature
	IR : More than $50 \mathrm{M}\Omega \cdot \mu\mathrm{F}$	1000+48/-0 hour
Temperature	Capacitance change: within ±2.5%	1 cycle condition
Cycling	Tan δ, IR : initial spec.	Min. operating temperature → 25°C
		→ Max. operating temperature → 25°C
		5 cycles test

## C. Recommended Soldering method :

Reflow ( Reflow Peak Temperature : 260+0/-5  $^{\circ}\!\!\mathrm{C}$  , 10sec. Max )

<sup>\*</sup> For the more detail Specification, Please refer to the Samsung MLCC catalogue.